IN THE CLAIMS

Please amend the claims to read as follows:

1 (Currently Amended): An oxynitride thermoelectric material, which has an element composition represented by the following formula (A):

$$AI_{z}Ga_{v}In_{x}M_{u}R_{v}O_{s}N_{t} \tag{A}$$

wherein M represents a transition element; R represents a rare earth element;

$$0 \leq z \leq 0.7, \ 0 \leq y \leq 0.7 \ \underline{0.1} \leq y \leq 0.3, \ 0.2 \leq x \leq 1.0, \ 0 \leq u \leq 0.7, \ 0 \leq v \leq 0.05,$$

 $0.9 \le s+t \le 1.7$ so that the element composition is an oxynitride, and $0.4 \le s \le 1.2$; and x+y+z=1, and

has an absolute value of a Seebeck coefficient of 40 $\mu\text{V/K}$ or more at a temperature of 100°C or more.

- 2 (Currently Amended): The oxynitride thermoelectric material according to claim 1, wherein the element composition has an electrical resistivity of 10^{-3} [[Ω cm]] Ω m or less.
- 3 (Previously Presented): The oxynitride thermoelectric material according to claim 1, wherein M in formula (A) is at least one transition element selected from Ni, Fe, Co and Mn.
- 4 (Previously Presented): The oxynitride thermoelectric material according to claim 1, wherein R in formula (A) is at least one rare earth element selected from Gd, Sc, Sm, Tb and Dy.
- 5 (Previously Presented): The oxynitride thermoelectric material according to claim 1, which comprises at least one having an amorphous structure.
- 6 (Currently Amended): A nitride thermoelectric material which has an element composition represented by formula (B):

$AI_zGa_yIn_xM_uR_vD_wN_m$

(B)

wherein M represents a transition element; R represents a rare earth element; D represents at least one element selected from elements of the Group IV or II; $0 \le z \le 0.7, \ 0 \le y \le 0.7, \ 0.2 \le x \le 1.0 \ 0.3 \le x \le 0.8, \ 0 \le u \le 0.7, \ 0 \le v \le 0.05, \ 0 \le w \le 0.2,$ and $0.9 \le m \le 1.1$; and x+y+z=1, and

has an absolute value of a Seebeck coefficient of 50 μ V/K or more at a temperature of 100°C or more, and an electrical resistivity of 10⁻³ [[Ω cm]] Ω m or less, wherein the composition has a non-amorphous structure.

7 (Previously Presented): The nitride thermoelectric material according to claim 6, wherein M in formula (B) is at least one transition element selected from Ni, Fe, Co and Mn.

8 (Previously Presented): The nitride thermoelectric material according to claim 6, wherein R in formula (B) is at least rare earth element selected from Gd, Sc, Sm and Tb.

9 (Original): The nitride thermoelectric material according to claim 6, wherein D in formula (B) is at least one element selected from Ge, Si, Mg and Zn.

10 (Previously Presented): The nitride thermoelectric material according to claim 6, which comprises at least one having a wurtzite crystal structure.

11 (canceled)